60 V, 1 A PNP medium power transistors Rev. 9 — 18 October 2011

#### 1. **Product profile**

### **1.1 General description**

PNP medium power transistor series in Surface-Mounted Device (SMD) plastic packages.

#### **Product overview** Table 1.

Type number <sup>[1]</sup>	Package	NPN complement		
	NXP	JEITA	JEDEC	
BCP52	SOT223	SC-73	-	BCP55
BCX52	SOT89	SC-62	TO-243	BCX55
BC52PA	SOT1061	-	-	BC55PA

[1] Valid for all available selection groups.

#### 1.2 Features and benefits

- High current
- Three current gain selections
- High power dissipation capability
- Exposed heatsink for excellent thermal and electrical conductivity (SOT89, SOT1061)
- Leadless very small SMD plastic package with medium power capability (SOT1061)
- AEC-Q101 gualified

#### 1.3 Applications

- Linear voltage regulators
- High-side switches
- Battery-driven devices
- Power management
- MOSFET drivers
- Amplifiers

### 1.4 Quick reference data

#### Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CEO}$	collector-emitter voltage	open base	-	-	-60	V
I <sub>C</sub>	collector current		-	-	-1	А
I <sub>CM</sub>	peak collector current	single pulse; $t_p \le 1 \text{ ms}$	-	-	-2	А



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Table 2.	Quick reference data continued					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
h <sub>FE</sub>	DC current gain	$V_{CE} = -2 V;$ $I_{C} = -150 \text{ mA}$	63	-	250	
	h <sub>FE</sub> selection -10	$V_{CE} = -2 V;$ $I_{C} = -150 mA$	63	-	160	
	h <sub>FE</sub> selection -16	$V_{CE} = -2 V;$ $I_{C} = -150 \text{ mA}$	100	-	250	

### 2. Pinning information

Pin	Description	Simplified outline	Graphic symbol
SOT223			
1	base		
2	collector		2, 4
3	emitter		1
4	collector		3 sym028
SOT89			
1	emitter		
2	collector		2
3	base		3
SOT1061			
1	base		
2	emitter	3	3
3	collector		1
		1   2     Transparent top view	symors

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### 3. Ordering information

Table 4.         Ordering information					
Type number <sup>[1]</sup>	Package				
	Name	Description	Version		
BCP52	SC-73	plastic surface-mounted package with increased heatsink; 4 leads	SOT223		
BCX52	SC-62	plastic surface-mounted package; exposed die pad for good heat transfer; 3 leads	SOT89		
BC52PA	HUSON3	plastic thermal enhanced ultra thin small outline package; no leads; 3 terminals; body $2 \times 2 \times 0.65$ mm	SOT1061		

[1] Valid for all available selection groups.

### 4. Marking

Table 5.   Marking codes	
Type number	Marking code
BCP52	BCP52
BCP52-10	BCP52/10
BCP52-16	BCP52/16
BCX52	AE
BCX52-10	AG
BCX52-16	AM
BC52PA	BS
BC52-10PA	BT
BC52-16PA	BU

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### 5. Limiting values

Table 6. In accordai	Limiting values	n Rating System (IEC	C 60134).		
Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter	-	-60	V
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-60	V
V <sub>EBO</sub>	emitter-base voltage	open collector	-	-5	V
I <sub>C</sub>	collector current		-	-1	А
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms	-	-2	A
I <sub>B</sub>	base current		-	-0.3	А
I <sub>BM</sub>	peak base current	single pulse; $t_p \le 1 ms$	-	-0.3	A
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$			
	BCP52		<u>[1]</u> _	0.65	W
			[2]	1.00	W
			[3]	1.35	W
	BCX52		<u>[1]</u> _	0.50	W
			[2]	0.95	W
			[3]	1.35	W
	BC52PA		<u>[1]</u> _	0.42	W
			[2]	0.83	W
			[3]	1.10	W
			<u>[4]</u>	0.81	W
			[5]	1.65	W
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-55	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

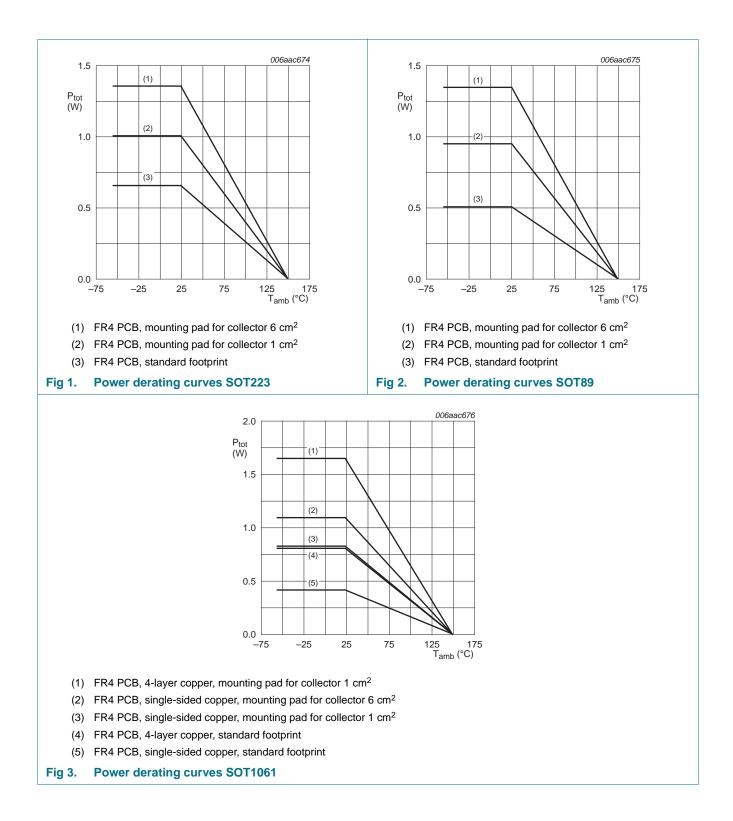
[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>.

[4] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.

[5] Device mounted on an FR4 PCB, 4-layer copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.

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### 6. Thermal characteristics

Table 7.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air				
	BCP52		<u>[1]</u> -	-	192	K/W
			[2] _	-	125	K/W
			[3]	-	93	K/W
BC>	BCX52		<u>[1]</u> -	-	250	K/W
			[2] _	-	132	K/W
			[3] _	-	93	K/W
BC	BC52PA		<u>[1]</u> -	-	298	K/W
			[2] _	-	151	K/W
			[3] _	-	114	K/W
			<u>[4]</u> _	-	154	K/W
			[5]	-	76	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point					
	BCP52		-	-	16	K/W
	BCX52		-	-	16	K/W
	BC52PA		-	-	20	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

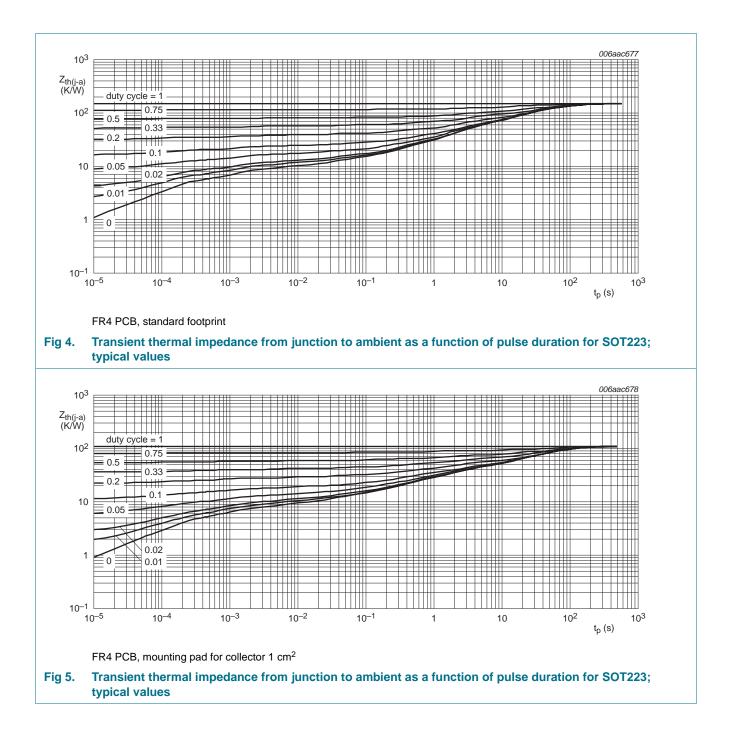
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>.

[4] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.

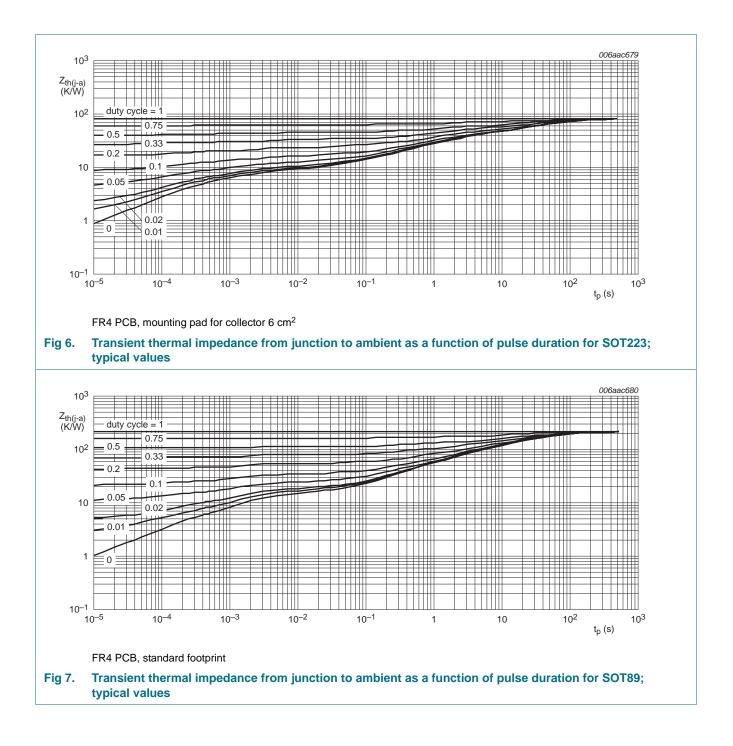
[5] Device mounted on an FR4 PCB, 4-layer copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.

# BCP52; BCX52; BC52PA



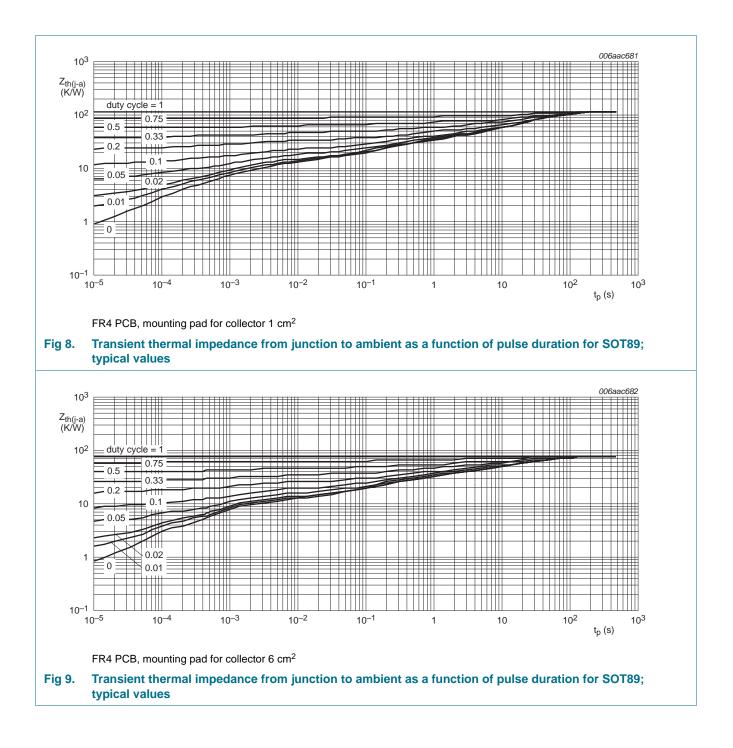
# BCP52; BCX52; BC52PA

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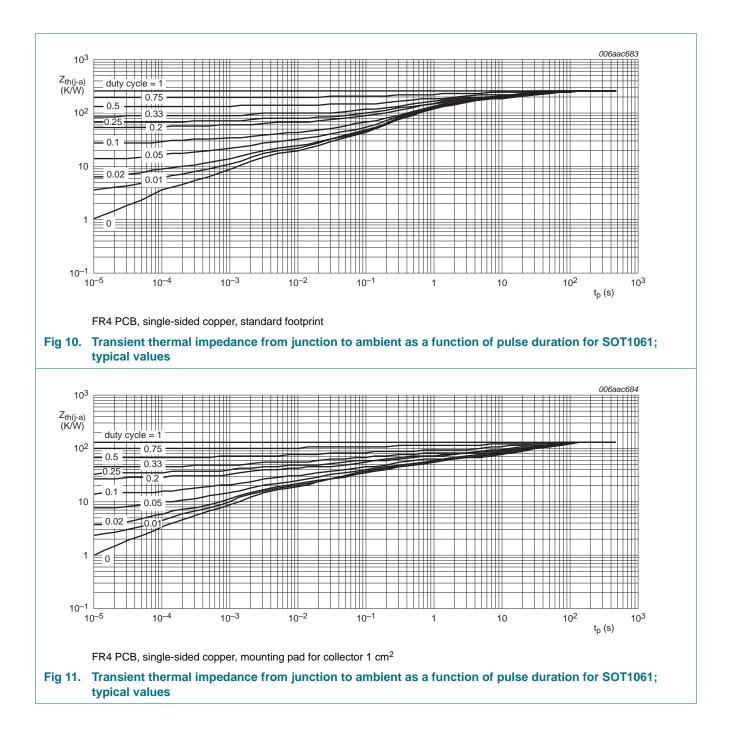


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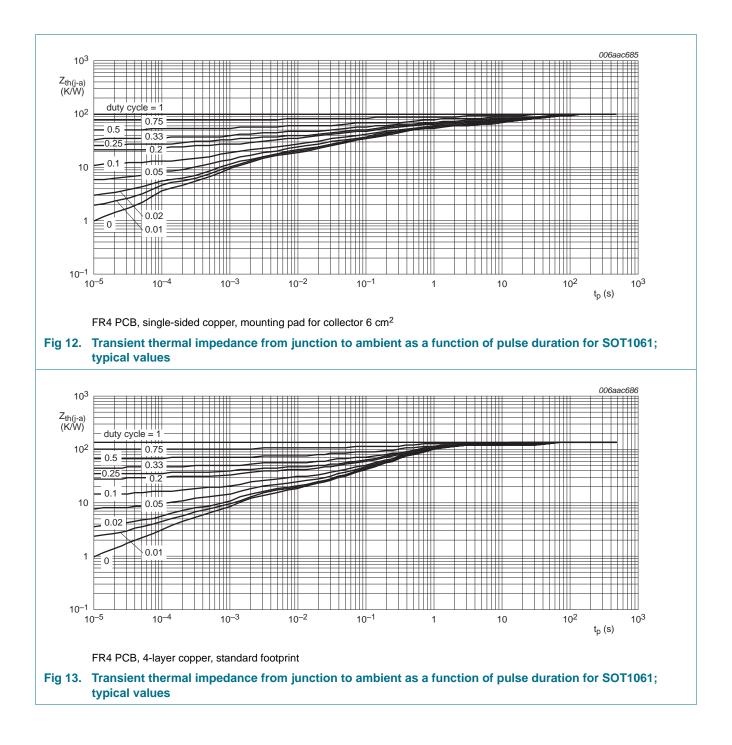
# BCP52; BCX52; BC52PA



# BCP52; BCX52; BC52PA

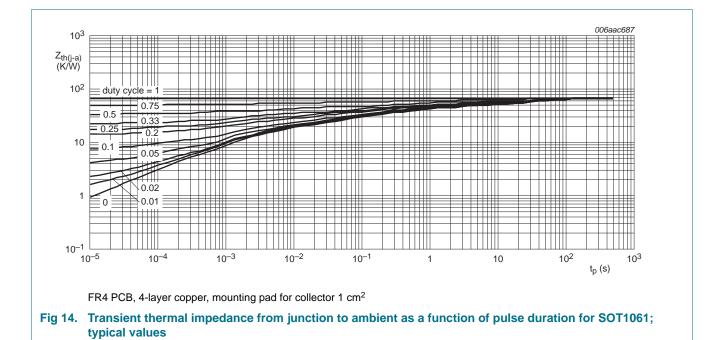


# BCP52; BCX52; BC52PA



# BCP52; BCX52; BC52PA

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### 7. Characteristics

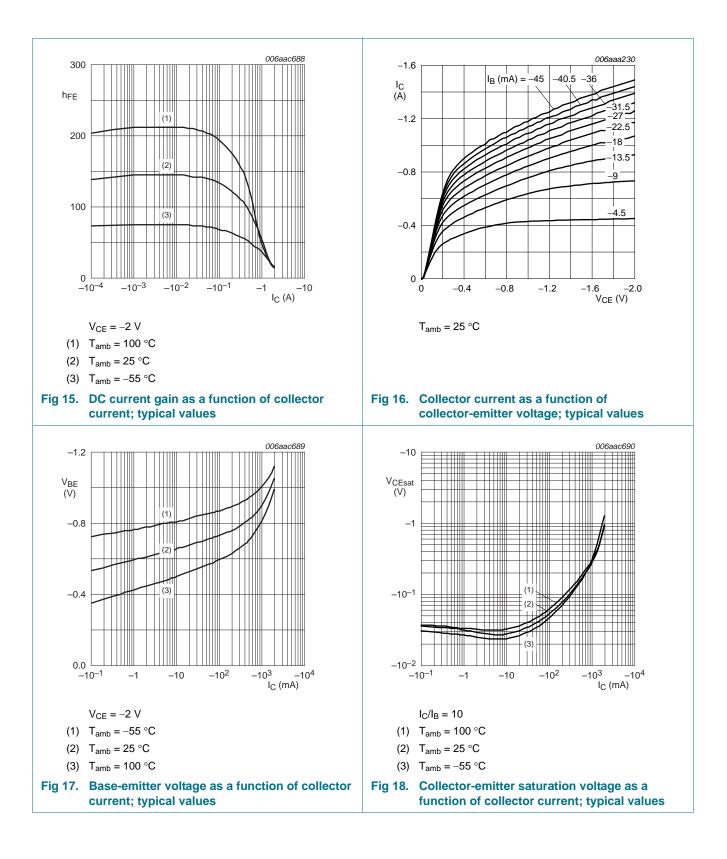
#### Table 8. Characteristics

 $T_{amb} = 25 \ ^{\circ}C$  unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off	$V_{CB} = -30 \text{ V}; I_E = 0 \text{ A}$		-	-	-100	nA
	current	$\label{eq:VCB} \begin{array}{l} V_{CB} = -30 \text{ V}; \text{ I}_{E} = 0 \text{ A}; \\ T_{j} = 150 \ ^{\circ}\text{C} \end{array}$		-	-	-10	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; \text{ I}_{C} = 0 \text{ A}$		-	-	-100	nA
h <sub>FE</sub>	DC current gain	$V_{CE} = -2 V$					
	$I_C = -5 \text{ mA}$		63	-	-		
	I <sub>C</sub> = -150 mA		63	-	250		
		I <sub>C</sub> = -500 mA	[1]	40	-	-	
	DC current gain	$V_{CE} = -2 V$					
	h <sub>FE</sub> selection -10	I <sub>C</sub> = -150 mA		63	-	160	
	h <sub>FE</sub> selection -16	I <sub>C</sub> = -150 mA		100	-	250	
V <sub>CEsat</sub>	collector-emitter saturation voltage	I <sub>C</sub> = -500 mA; I <sub>B</sub> = -50 mA	[1]	-	-	-0.5	V
V <sub>BE</sub>	base-emitter voltage	$V_{CE} = -2 \text{ V}; \text{ I}_{C} = -500 \text{ mA}$	[1]	-	-	-1	V
C <sub>c</sub>	collector capacitance	$\label{eq:VCB} \begin{array}{l} V_{CB}=-10 \text{ V}; \text{ I}_{E}=\text{i}_{e}=0 \text{ A};\\ \text{ f}=1 \text{ MHz} \end{array}$		-	15	-	pF
f <sub>T</sub>	transition frequency	$V_{CE} = -5 \text{ V}; I_C = -50 \text{ mA};$ f = 100 MHz		-	145	-	MHz

[1] Pulse test:  $t_p \le 300 \ \mu$ s;  $\delta = 0.02$ .

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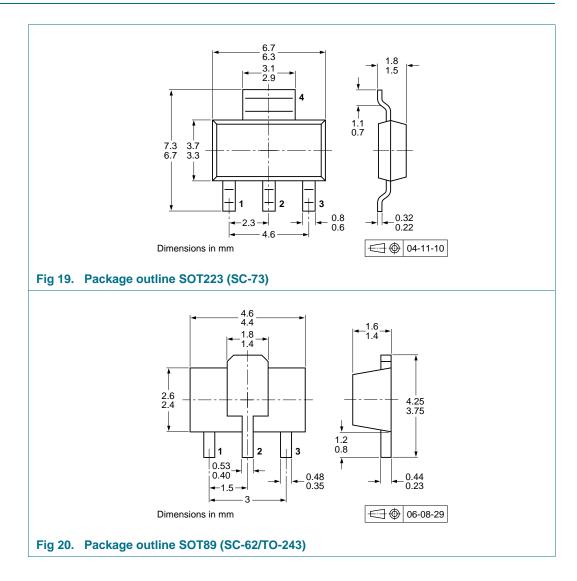
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### 8. Test information

#### 8.1 Quality information

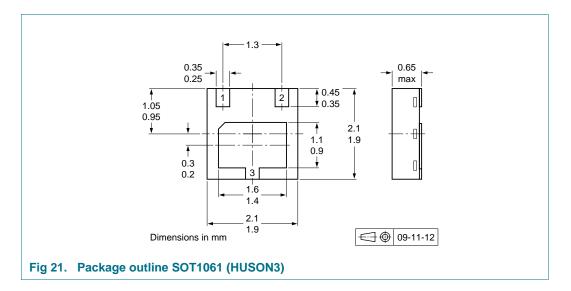
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

### 9. Package outline



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### **10. Packing information**

#### Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Package	Description			Packing quantity		
			1000	3000	4000	
SOT223	8 mm pitch, 12 mm tape and reel		-115	-	-135	
SOT89	8 mm pitch, 12 mm tape and reel; T1	[3]	-115	-	-135	
	8 mm pitch, 12 mm tape and reel; T3	[4]	-146	-	-	
SOT1061	4 mm pitch, 8 mm tape and reel		-	-115	-	
	SOT223 SOT89	SOT2238 mm pitch, 12 mm tape and reelSOT898 mm pitch, 12 mm tape and reel; T18 mm pitch, 12 mm tape and reel; T3	SOT2238 mm pitch, 12 mm tape and reelSOT898 mm pitch, 12 mm tape and reel; T18 mm pitch, 12 mm tape and reel; T3[4]	SOT223         8 mm pitch, 12 mm tape and reel         -115           SOT89         8 mm pitch, 12 mm tape and reel; T1         3         -115           8 mm pitch, 12 mm tape and reel; T1         4         -146	Image: Non-Sort223         8 mm pitch, 12 mm tape and reel         -115         -           SOT89         8 mm pitch, 12 mm tape and reel; T1         3         -115         -           8 mm pitch, 12 mm tape and reel; T1         3         -115         -           8 mm pitch, 12 mm tape and reel; T3         4         -146         -	

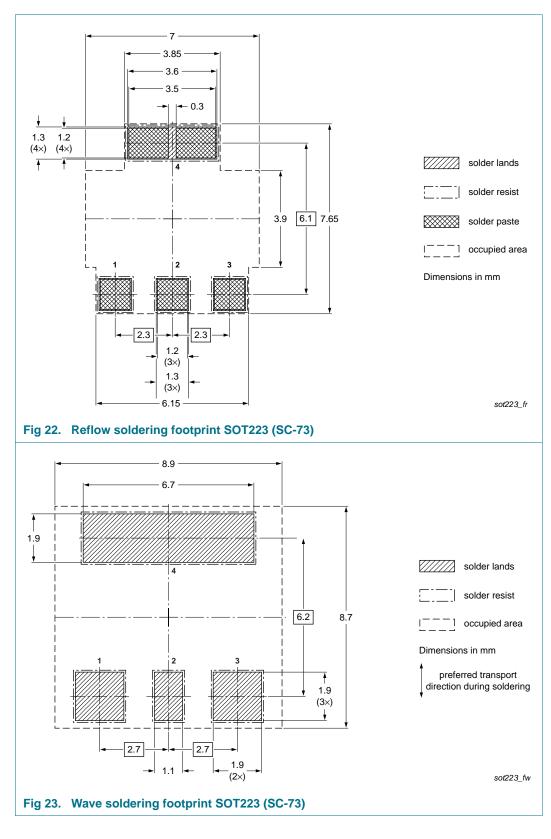
[1] For further information and the availability of packing methods, see <u>Section 14</u>.

[2] Valid for all available selection groups.

- [3] T1: normal taping
- [4] T3: 90° rotated taping

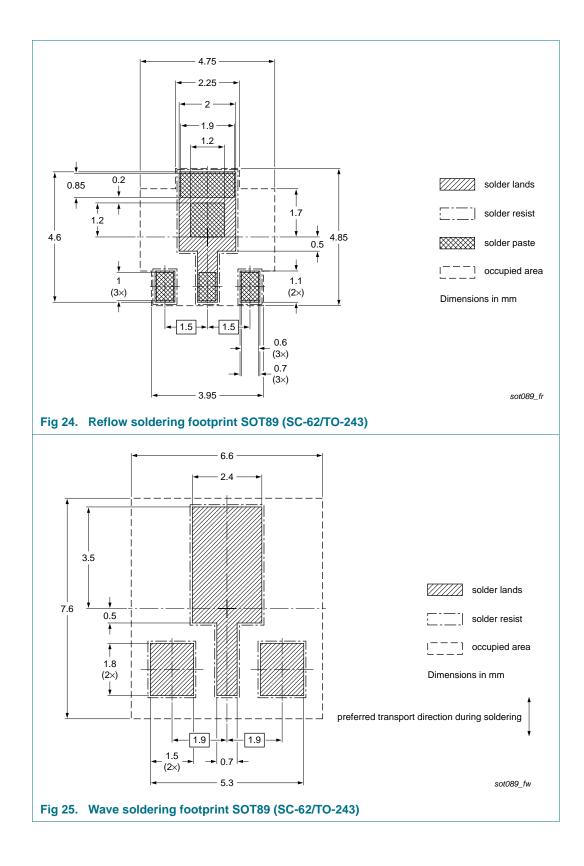
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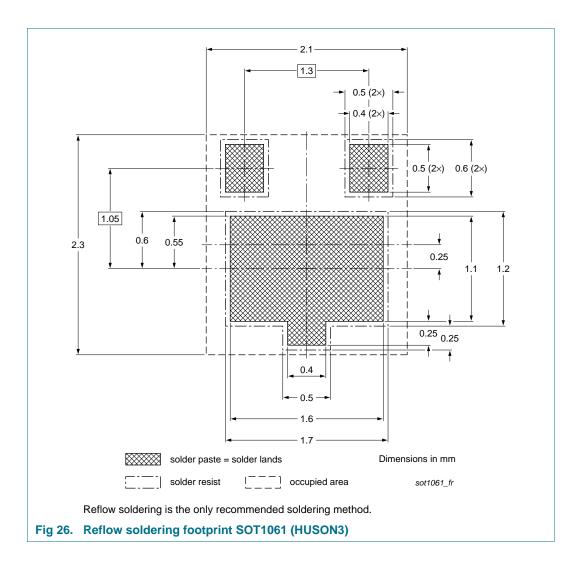
### 11. Soldering



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### 12. Revision history

#### Table 10.Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BCP52_BCX52_BC52PA v.9	20111018	Product data sheet	-	BCP52_BCX52 v.8
Modifications:	<ul> <li>Added Type</li> </ul>	e numbers: BC52PA, BC	52-10PA and BC52-	16PA
	<ul> <li>Section 1 "I</li> </ul>	Product profile": updated		
	• <u>Table 6</u> and	I <u>7</u> : updated according to	latest measuremen	its
	<ul> <li>Figure 1 to</li> </ul>	<u>9, 15, 17, 18</u> and <u>21</u> : upc	lated	
	<ul> <li>Figure 10 to</li> </ul>	o <u>14</u> : added		
	Section 8 "	Test information": added		
	Section 11	"Soldering": added		
	<ul> <li>Section 13</li> </ul>	"Legal information": upda	ited	
BCP52_BCX52 v.8	20080225	Product data sheet	-	BC638_BCP52_BCX52 v.7
BC638_BCP52_BCX52 v.7	20070626	Product data sheet	-	BC638_BCP52_BCX52 v.6
BC638_BCP52_BCX52 v.6	20060329	Product data sheet	-	BC636_638_640 v.5
				BCP51_52_53 v.5
D0000 000 040 5	00044044			BCX51_52_53 v.4
BC636_638_640 v.5	20041011	Product specification	-	BC636_638_640 v.4
BCP51_52_53 v.5	20030206	Product specification	-	BCP51_52_53 v.4
BCX51_52_53 v.4	20011010	Product specification	-	BCX51_52_53 v.3

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### 13. Legal information

#### 13.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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